## NSN 5961-01-324-5892

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-324-5892 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.085 inches and 0.105 inches **End Application:** 5805-01-188-3993 central office, telephone, automatic **Mounting Method: Terminal Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 22.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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